

## ISO734x Robust EMC, Low Power, Quad-Channel Digital Isolators

### 1 Features

- Signaling Rate: 25 Mbps
- Integrated Noise Filter on the Inputs
- Default Output 'High' and 'Low' Options
- Low Power Consumption, Typical  $I_{CC}$  per Channel at 1 Mbps:
  - ISO7340: 0.9 mA (5 V Supplies),  
0.7 mA (3.3 V Supplies)
  - ISO7341: 1.2 mA (5 V Supplies),  
0.9 mA (3.3 V Supplies)
  - ISO7342: 1.3 mA (5 V Supplies),  
0.9 mA (3.3 V Supplies)
- Low Propagation Delay: 31 ns  
Typical (5 V Supplies)
- 3.3 V and 5 V Level Translation
- Wide Temperature Range:  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$
- 70 KV/ $\mu\text{s}$  Transient Immunity,  
Typical (5 V Supplies)
- Robust Electromagnetic Compatibility (EMC)
  - System-level ESD, EFT, and Surge Immunity
  - Low Emissions
- Operates from 3.3 V and 5 V Supplies
- Wide Body SOIC-16 Package
- Safety and Regulatory Approvals:
  - 4242 V<sub>PK</sub> Basic Isolation per DIN V VDE V 0884-10 and DIN EN 61010-1
  - 3 KV<sub>RMS</sub> Isolation for 1 minute per UL 1577
  - CSA Component Acceptance Notice 5A, IEC 60950-1 and IEC 61010-1 End Equipment Standards
  - GB4943.1-2011 CQC Certification

### 2 Applications

- Optocoupler Replacement in:
  - Industrial Fieldbus
    - Profibus
    - Modbus
    - DeviceNet™ Data Buses
  - Servo Control Interface
  - Motor Control
  - Power Supplies
  - Battery Packs

### 3 Description

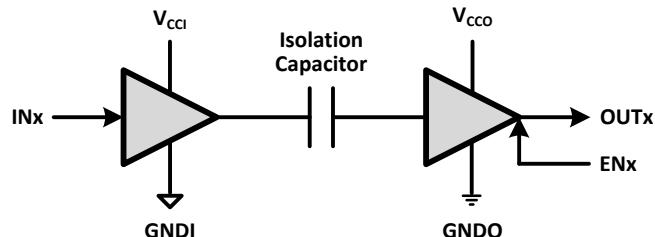
ISO734x provide galvanic isolation up to 3000 V<sub>RMS</sub> for 1 minute per UL and 4242 V<sub>PK</sub> per VDE. These devices have four isolated channels comprised of logic input and output buffers separated by a silicon dioxide (SiO<sub>2</sub>) insulation barrier. ISO7340 has four channels in forward direction, ISO7341 has three forward and one reverse-direction channels; and ISO7342 has two forward and two reverse-direction channels. In case of input power or signal loss, default output is 'low' for devices with suffix 'F' and 'high' for devices without suffix 'F'. See [Device Functional Modes](#) for further details. Used in conjunction with isolated power supplies, these devices prevent noise currents on a data bus or other circuits from entering the local ground and interfering with or damaging sensitive circuitry. ISO734x has integrated noise filter for harsh industrial environment where short noise pulses may be present at the device input pins. ISO734x has TTL input thresholds and operates from 3 V to 5.5 V supply levels. Through innovative chip design and layout techniques, electromagnetic compatibility of ISO734x has been significantly enhanced to enable system-level ESD, EFT, Surge and Emissions compliance.

#### Device Information<sup>(1)</sup>

ORDER NUMBER	PACKAGE	BODY SIZE
ISO7340C	SOIC (16)	10.3mm x 7.50mm
ISO7340FC		
ISO7341C		
ISO7341FC		
ISO7342C		
ISO7342FC		

(1) For all available packages, see the orderable addendum at the end of the datasheet.

#### Simplified Schematic



(1) V<sub>CCI</sub> and GNDI are supply and ground connections respectively for the input channels.

(2) V<sub>CCO</sub> and GNDI are supply and ground connections respectively for the output.



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (March 2015) to Revision E	Page
• Deleted "(VDE V0884-10):2006-12" and "(VDE 0411-1:2011-07)" from the <i>Features Safety and Regulatory Approvals</i> :....	1
• Deleted "(Approval Pending)" From the CSA Component Acceptance list item in the <i>Features</i> .....	1
• Changed From: $V_{CC1}$ To: $V_{CCI}$ in <i>Figure 13</i> .....	13
• Changed From: $V_{CC1}$ To: $V_{CCI}$ and From: $V_{CC2}$ To: $V_{CCO}$ in <i>Figure 16</i> .....	14
• Deleted IEC from the section title: <i>Insulation and Safety-Related Specifications for DW-16 Package</i> .....	16
• Changed the TEST Conditions of CTI in <i>Insulation and Safety-Related Specifications for DW-16 Package</i> .....	16
• Changed the Test Conditions of $V_{ISO}$ in <i>Insulation Characteristics</i> .....	17
• Changed column CSA in the <i>Regulatory Information</i> table .....	17

Changes from Revision C (December 2014) to Revision D	Page
• Changed the DIN V VDE 0884-10 number in the <i>Features Safety and Regulatory Approvals</i> : .....	1
• Added "(Approval Pending)" to the CSA Component Acceptance list item in the <i>Features</i> .....	1
• Deleted "All Agencies Approvals Planned" from the <i>Features Safety and Regulatory Approvals</i> : .....	1
• Changed the Simplified Schematic: $V_{CC1}$ To $V_{CCI}$ , $V_{CC2}$ to $V_{CCO}$ and GND1 to GNDI, GND2 to GNDO. Added Notes 1 and 2.....	1
• Added Note: "Maximum voltage must not exceed 6 V:" to <i>Absolute Maximum Ratings</i> <sup>(1)</sup> .....	5
• Changed MIN value for $V_{OH}$ in the <i>Electrical Characteristics</i> From: $V_{CCx} - 0.5$ To: $V_{CCO} - 0.5$ .....	7
• Changed $V_{CCx}$ To $V_{CCO}$ in Note 1 of the <i>Electrical Characteristics</i> .....	7
• Changed MIN value for $V_{OH}$ in the <i>Electrical Characteristics</i> From: $V_{CCx} - 0.5$ To: $V_{CCO} - 0.5$ .....	9
• Changed $V_{CCx}$ To $V_{CCO}$ in Note 1 of the <i>Electrical Characteristics</i> .....	9
• Added "DT1" to the Minimum internal gap in <i>Insulation and Safety-Related Specifications for DW-16 Package</i> .....	16
• Changed $V_{IORM}$ "Maximum repetitive peak voltage" To: "Maximum repetitive peak isolation voltage per DIN V VDE V 0884-10" in <i>Insulation Characteristics</i> .....	17
• Changed $V_{PR}$ From: "DIN V VDE 0884-10 " To: "DIN V VDE V 0884-10" in <i>Insulation Characteristics</i> .....	17

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• Changed $V_{IOTM}$ From: "DIN V VDE 0884-10" To: "DIN V VDE V 0884-10" in <i>Insulation Characteristics</i>	17
• Changed $V_{IOSM}$ "Maximum surge voltage per DIN V VDE 0884-10" To: "Maximum surge isolation voltage per DIN V VDE V 0884-100" in <i>Insulation Characteristics</i>	17
• Changed $V_{IOSM}$ Test Conditions in <i>Insulation Characteristics</i>	17
• Changed $R_S$ Test Conditions in <i>Insulation Characteristics</i> From: $T_S$ To: $T_S = 150^\circ\text{C}$	17
• Changed the <i>Regulatory Information</i> table	17
• Changed title From: " IEC Safety Limiting Values" To: <i>Safety Limiting Values</i>	18
• Changed <b>Table 2</b> Header information From: INPUT-SIDE $V_{CC}$ To: $V_{CC_1}$ and OUTPUT-SIDE $V_{CC}$ To: $V_{CC_0}$	18
• Changed <b>Figure 19</b> From: $V_{CC}$ To: $V_{CC_1}$ on the inputs and $V_{CC_0}$ on Output and Enabled	19
• Moved <b>Figure 21</b> to <b>Figure 23</b> from the <i>Design Requirements</i> section to the <i>Detailed Design Procedure</i> section	21

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<b>Changes from Revision B (November 2014) to Revision C</b>	<b>Page</b>
• Changed the Handling Ratings table to <i>ESD Ratings</i>	5
• Changed the $I_{CC2}$ , Supply current, DC to 1 Mbps TYP value From: 3 To 3.2 mA	7
• Changed the $I_{CC2}$ , Supply current, 10 Mbps TYP value From: 5.1 To 5.6 mA	7
• Changed the $I_{CC2}$ , Supply current, 25 Mbps TYP value From: 8.6 To 9.3 mA	7
• Changed the $I_{CC1}$ , Supply current, 10 Mbps TYP value From: 0.8 To 0.9 mA	9
• Changed the $I_{CC2}$ , Supply current, 10 Mbps TYP value From: 0.3.6 To 3.9 mA	9
• Changed the $I_{CC2}$ , Supply current, 25 Mbps TYP value From: 5.9 To 6.3 mA	9
• Added <b>Figure 1</b> and <b>Figure 2</b>	11
• Changed <b>Figure 4</b>	11
• Changed Minimum internal gap MIN value in <i>Insulation and Safety-Related Specifications for DW-16 Package</i> From: 0.014 mm To: 13.5 $\mu\text{m}$	16
• Changed Minimum internal gap MIN value in <i>Insulation and Safety-Related Specifications for DW-16 Package</i> From: 13.5 $\mu\text{m}$ To: 13 $\mu\text{m}$	16
• Delete text "per DIN V VDE 0884-10" from $V_{IORM}$ in the table in section <i>Insulation Characteristics</i>	17
• Changed From: $V_{PEAK}$ To $V_{PK}$ in the UNIT column of the table in section <i>Insulation Characteristics</i>	17
• Added $V_{IOSM}$ to the table in section <i>Insulation Characteristics</i>	17
• Changed the table in <i>Regulatory Information</i> section - removed text "Certified according to", "Approved under", "Recognized under", changed "pending" To: "planned"	17
• Changed Maximum Repetitive Peak Voltage, 1414 $V_{PK}$ To: Maximum surge voltage , 6000 $V_{PK}$ in the VDE column of the table in section <i>Regulatory Information</i>	17

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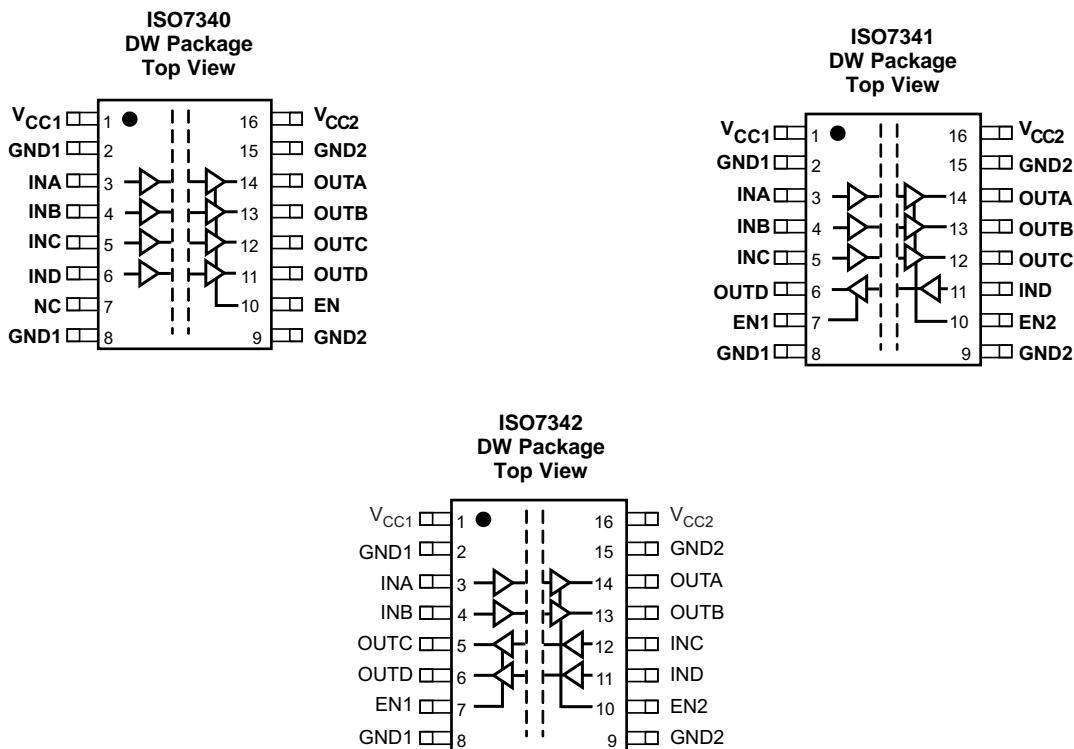
<b>Changes from Revision A (Octoberr 2014) to Revision B</b>	<b>Page</b>
• Added <b>Figure 3</b> and <b>Figure 4</b>	11
• Changed the $R_{IO}$ Test Conditions in <i>Insulation and Safety-Related Specifications for DW-16 Package</i> : Added $T_A = 25^\circ\text{C}$ at $\text{MIN} = 10^{12}$	16
• Changed the $R_{IO}$ Test Conditions in <i>Insulation and Safety-Related Specifications for DW-16 Package</i> : Added $V_{IO} = 500 \text{ V}$ , $100^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ at $\text{MIN} = 10^{11}$	16
• Added Test Condition to <b>Table 1</b> : Rated mains voltage $\leq 1000 \text{ V}_{\text{RMS}}$	17

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<b>Changes from Original (September 2014) to Revision A</b>	<b>Page</b>
• Changed From a 1 page Product Preview to the full datasheet	1
• Changed the <i>Simplified Schematic</i> , added ground symbols	1

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## 5 Pin Configuration and Functions



### Pin Functions

PIN				I/O	DESCRIPTION
NAME	ISO7340	ISO7341	ISO7342		
INA	3	3	3	I	Input, channel A
INB	4	4	4	I	Input, channel B
INC	5	5	12	I	Input, channel C
IND	6	11	11	I	Input, channel D
OUTA	14	14	14	O	Output, channel A
OUTB	13	13	13	O	Output, channel B
OUTC	12	12	5	O	Output, channel C
OUTD	11	6	6	O	Output, channel D
EN1	–	7	7	I	Output enable 1. Output pins on side-1 are enabled when EN1 is high or disconnected and disabled when EN1 is low.
EN2	–	10	10	I	Output enable 2. Output pins on side-2 are enabled when EN2 is high or disconnected and disabled when EN2 is low.
EN	10	–	–	I	Output enable. All output pins are enabled when EN is high or disconnected and disabled when EN is low.
V <sub>CC1</sub>	1	1	1	–	Power supply, V <sub>CC1</sub>
V <sub>CC2</sub>	16	16	16	–	Power supply, V <sub>CC2</sub>
GND1	2,8	2,8	2,8	–	Ground connection for V <sub>CC1</sub>
GND2	9,15	9,15	9,15	–	Ground connection for V <sub>CC2</sub>
NC	7	–	–	–	No Connect pins are floating with no internal connection

## 6 Specifications

### 6.1 Absolute Maximum Ratings<sup>(1)</sup>

		MIN	MAX	UNIT
Supply voltage <sup>(2)</sup>	V <sub>CC1</sub> , V <sub>CC2</sub>	-0.5	6	V
Voltage	INx, OUTx, ENx	-0.5	V <sub>CC</sub> + 0.5 <sup>(3)</sup>	V
Output Current, I <sub>O</sub>			±15	mA
Maximum junction temperature, T <sub>J</sub>			150	°C
Storage temperature, T <sub>stg</sub>		-65	150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values except differential I/O bus voltages are with respect to the local ground terminal (GND1 or GND2) and are peak voltage values.
- (3) Maximum voltage must not exceed 6 V.

### 6.2 ESD Ratings

			VALUE	UNIT
V <sub>ESD</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±4000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±1500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

PARAMETER		MIN	TYP	MAX	UNIT
V <sub>CC1</sub> , V <sub>CC2</sub>	Supply voltage	3		5.5	V
I <sub>OH</sub>	High-level output current		-4		mA
I <sub>OL</sub>	Low-level output current			4	mA
V <sub>IH</sub>	High-level input voltage		2	5.5	V
V <sub>IL</sub>	Low-level input voltage		0	0.8	V
t <sub>ui</sub>	Input pulse duration		40		ns
1 / t <sub>ui</sub>	Signaling rate		0	25	Mbps
T <sub>J</sub>	Junction temperature <sup>(1)</sup>			136	°C
T <sub>A</sub>	Ambient temperature	-40	25	125	°C

- (1) To maintain the recommended operating conditions for T<sub>J</sub>, see the *Thermal Information* table.

## 6.4 Thermal Information

THERMAL METRIC		DW (16 Pins)	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	78.4	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC(\text{top})}$	Junction-to-case(top) thermal resistance	41.0	
$R_{\theta JB}$	Junction-to-board thermal resistance	43.0	
$\Psi_{JT}$	Junction-to-top characterization parameter	15.6	
$\Psi_{JB}$	Junction-to-board characterization parameter	42.5	
$R_{\theta JC(\text{bottom})}$	Junction-to-case(bottom) thermal resistance	n/a	
$P_D$	Maximum Power Dissipation by ISO7340	V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15pF, Input a 12.5 MHz 50% duty cycle square wave	92
$P_{D1}$	Maximum Power Dissipation by Side-1 of ISO7340	24	mW
$P_{D2}$	Maximum Power Dissipation by Side-2 of ISO7340		
$P_D$	Maximum Power Dissipation by ISO7341	V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15pF, Input a 12.5 MHz 50% duty cycle square wave	102
$P_{D1}$	Maximum Power Dissipation by Side-1 of ISO7341	42	mW
$P_{D2}$	Maximum Power Dissipation by Side-2 of ISO7341		
$P_D$	Maximum Power Dissipation by ISO7342	V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15pF, Input a 12.5 MHz 50% duty cycle square wave	111
$P_{D1}$	Maximum Power Dissipation by Side-1 of ISO7342	55.5	mW
$P_{D2}$	Maximum Power Dissipation by Side-2 of ISO7342		

## 6.5 Electrical Characteristics

$V_{CC1}$  and  $V_{CC2}$  at  $5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT		
$V_{OH}$	High-level output voltage	$I_{OH} = -4\text{ mA}$ ; see <a href="#">Figure 13</a>		$V_{CCO}^{(1)} - 0.5$	4.7		V		
		$I_{OH} = -20\text{ }\mu\text{A}$ ; see <a href="#">Figure 13</a>		$V_{CCO}^{(1)} - 0.1$		5			
$V_{OL}$	Low-level output voltage	$I_{OL} = 4\text{ mA}$ ; see <a href="#">Figure 13</a>		0.2	0.4		V		
		$I_{OL} = 20\text{ }\mu\text{A}$ ; see <a href="#">Figure 13</a>		0		0.1			
$V_{I(HYS)}$	Input threshold voltage hysteresis			480			mV		
$I_{IH}$	High-level input current	$V_{IH} = V_{CC}$ at $IN_x$ or $EN_x$		10			$\mu\text{A}$		
$I_{IL}$	Low-level input current	$V_{IL} = 0\text{ V}$ at $IN_x$ or $EN_x$		-10					
CMTI	Common-mode transient immunity	$V_I = V_{CC}$ or $0\text{ V}$ ; see <a href="#">Figure 16</a>		25	70		kV/ $\mu\text{s}$		
<b>Supply Current (All inputs switching with square wave clock signal for dynamic <math>I_{CC}</math> measurement)</b>									
<b>ISO7340</b>									
$I_{CC1}$	Supply current	Disable	EN = 0 V	0.6	1.4		mA		
$I_{CC2}$				0.4		0.8			
$I_{CC1}$		DC to 1 Mbps	DC Signal: $V_I = V_{CC}$ or $0\text{ V}$ , AC Signal: All channels switching with square wave clock input; $C_L = 15\text{ pF}$	0.6	1.4				
$I_{CC2}$				3.2		4.8			
$I_{CC1}$		10 Mbps		1.4	2.3				
$I_{CC2}$				5.6		7.1			
$I_{CC1}$		25 Mbps		2.7	4				
$I_{CC2}$				9.3		12			
<b>ISO7341</b>									
$I_{CC1}$	Supply current	Disable	EN1 = EN2 = 0 V	0.8	1.8		mA		
$I_{CC2}$				0.7		1.3			
$I_{CC1}$		DC to 1 Mbps	DC Signal: $V_I = V_{CC}$ or $0\text{ V}$ , AC Signal: All channels switching with square wave clock input; $C_L = 15\text{ pF}$	2	3.2				
$I_{CC2}$				2.9		4.4			
$I_{CC1}$		10 Mbps		3.2	4.5				
$I_{CC2}$				4.9		6.5			
$I_{CC1}$		25 Mbps		5	7				
$I_{CC2}$				7.8		11			
<b>ISO7342</b>									
$I_{CC1}, I_{CC2}$	Supply current	Disable	EN1 = EN2 = 0 V	0.7	1.6		mA		
$I_{CC1}, I_{CC2}$				2.5		4			
$I_{CC1}, I_{CC2}$		DC to 1 Mbps	DC Signal: $V_I = V_{CC}$ or $0\text{ V}$ , AC Signal: All channels switching with square wave clock input; $C_L = 15\text{ pF}$	4.1	5.6				
$I_{CC1}, I_{CC2}$				6.4		9			

(1)  $V_{CCO}$  is supply voltage,  $V_{CC1}$  or  $V_{CC2}$ , for the output channel being measured.

## 6.6 Switching Characteristics

$V_{CC1}$  and  $V_{CC2}$  at  $5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}, t_{PHL}$ Propagation delay time	See Figure 13	20	31	58	ns
PWD <sup>(1)</sup> Pulse width distortion $ t_{PHL} - t_{PLH} $				4	
$t_{sk(o)}$ <sup>(2)</sup> Channel-to-channel output skew time	Same-direction Channels			2.5	ns
	Opposite-direction Channels			17	
$t_{sk(pp)}$ <sup>(3)</sup> Part-to-part skew time				23	
$t_r$ Output signal rise time	See Figure 13			2.1	ns
$t_f$ Output signal fall time				1.7	
$t_{PHZ}$ Disable Propagation Delay, high-to-high impedance output				7	ns
$t_{PLZ}$ Disable Propagation Delay, low-to-high impedance output				7	
$t_{PZH}$ Enable Propagation Delay, high impedance-to-high output	ISO734xC			7	
	ISO734xFC			15000	
$t_{PZL}$ Enable Propagation Delay, high impedance-to-low output	ISO734xC			15000	<sup>(4)</sup>
	ISO734xFC			23000	
$t_{fs}$ Fail-safe output delay time from input power loss	See Figure 15			7	ns
				13	
				9.4	μs

- (1) Also known as Pulse Skew.
- (2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
- (3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.
- (4) The enable signal rate should be  $\leq 43$  Kbps.

## 6.7 Electrical Characteristics

$V_{CC1}$  and  $V_{CC2}$  at  $3.3\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT		
$V_{OH}$	High-level output voltage	$I_{OH} = -4\text{ mA}$ ; see <a href="#">Figure 13</a>		$V_{CCO}^{(1)}$ –0.5	3		V		
		$I_{OH} = -20\text{ }\mu\text{A}$ ; see <a href="#">Figure 13</a>		$V_{CCO}^{(1)}$ –0.1	3.3				
$V_{OL}$	Low-level output voltage	$I_{OL} = 4\text{ mA}$ ; see <a href="#">Figure 13</a>		0.2	0.4		V		
		$I_{OL} = 20\text{ }\mu\text{A}$ ; see <a href="#">Figure 13</a>		0	0.1				
$V_{I(HYS)}$	Input threshold voltage hysteresis			450			mV		
$I_{IH}$	High-level input current	$V_{IH} = V_{CC}$ at INx or ENx		10			$\mu\text{A}$		
$I_{IL}$	Low-level input current	$V_{IL} = 0\text{ V}$ at INx or ENx		-10					
CMTI	Common-mode transient immunity	$V_I = V_{CC}$ or 0 V; see <a href="#">Figure 16</a>		25	50		kV/ $\mu\text{s}$		
<b>Supply Current (All inputs switching with square wave clock signal for dynamic <math>I_{CC}</math> measurement)</b>									
<b>ISO7340</b>									
$I_{CC1}$	Supply current	Disable	EN = 0 V	0.4	0.7		mA		
$I_{CC2}$				0.3	0.6				
$I_{CC1}$		DC to 1 Mbps	DC Signal: $V_I = V_{CC}$ or 0 V, AC Signal: All channels switching with square wave clock input; $C_L = 15\text{ pF}$	0.4	0.7				
$I_{CC2}$				2.3	3.6				
$I_{CC1}$		10 Mbps		0.9	1.3				
$I_{CC2}$				3.9	5.1				
$I_{CC1}$		25 Mbps		1.6	2.4				
$I_{CC2}$				6.3	8				
<b>ISO7341</b>									
$I_{CC1}$	Supply current	Disable	EN1 = EN2 = 0 V	0.6	1		mA		
$I_{CC2}$				0.5	0.8				
$I_{CC1}$		DC to 1 Mbps	DC Signal: $V_I = V_{CC}$ or 0 V, AC Signal: All channels switching with square wave clock input; $C_L = 15\text{ pF}$	1.4	2.3				
$I_{CC2}$				2.2	3.2				
$I_{CC1}$		10 Mbps		2.2	3				
$I_{CC2}$				3.4	4.5				
$I_{CC1}$		25 Mbps		3.3	4.7				
$I_{CC2}$				5.2	7.2				
<b>ISO7342</b>									
$I_{CC1}, I_{CC2}$	Supply current	Disable	EN1 = EN2 = 0 V	0.5	0.9		mA		
$I_{CC1}, I_{CC2}$		DC to 1 Mbps	DC Signal: $V_I = V_{CC}$ or 0 V, AC Signal: All channels switching with square wave clock input; $C_L = 15\text{ pF}$	1.8	2.8				
$I_{CC1}, I_{CC2}$		10 Mbps		2.8	4				
$I_{CC1}, I_{CC2}$		25 Mbps		4.3	5.8				

(1)  $V_{CCO}$  is supply voltage,  $V_{CC1}$  or  $V_{CC2}$ , for the output channel being measured.

## 6.8 Switching Characteristics

$V_{CC1}$  and  $V_{CC2}$  at  $3.3\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}, t_{PHL}$ Propagation delay time	See <a href="#">Figure 13</a>	22	35	66	ns
PWD <sup>(1)</sup> Pulse width distortion $ t_{PHL} - t_{PLH} $				2.5	
$t_{sk(o)}$ <sup>(2)</sup> Channel-to-channel output skew time	Same-direction Channels			3	ns
	Opposite-direction Channels			16	
$t_{sk(pp)}$ <sup>(3)</sup> Part-to-part skew time				28	
$t_r$ Output signal rise time	See <a href="#">Figure 13</a>			2.8	ns
$t_f$ Output signal fall time				2.1	
$t_{PHZ}$ Disable Propagation Delay, high-to-high impedance output				9	18
$t_{PLZ}$ Disable Propagation Delay, low-to-high impedance output				9	18
$t_{PZH}$ Enable Propagation Delay, high impedance-to-high output	ISO734xC			9	18
	ISO734xFC			16	24000 <sup>(4)</sup>
$t_{PZL}$ Enable Propagation Delay, high impedance-to-low output	ISO734xC			16	24000 <sup>(4)</sup>
	ISO734xFC			9	18
$t_{fs}$ Fail-safe output delay time from input power loss	See <a href="#">Figure 15</a>			9.4	μs

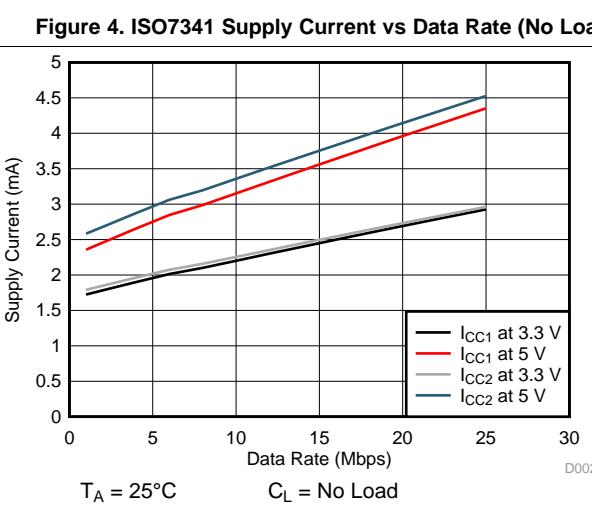
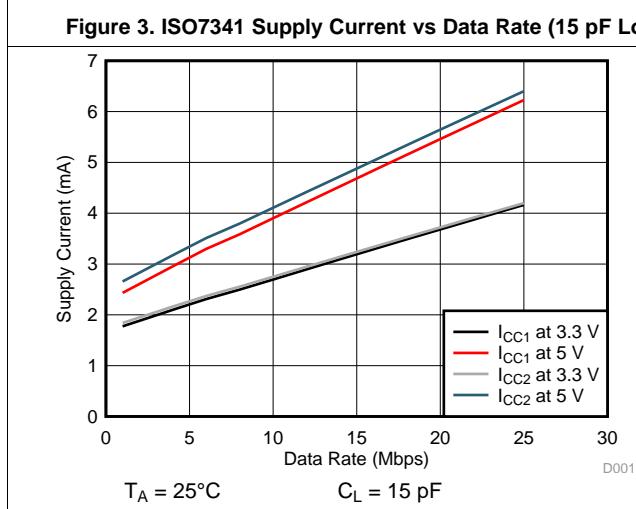
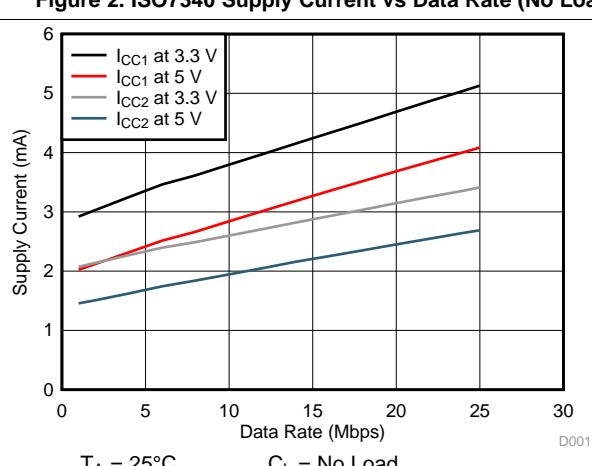
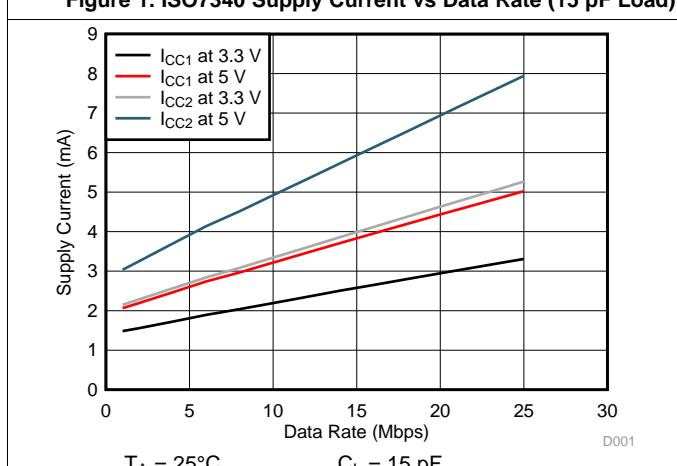
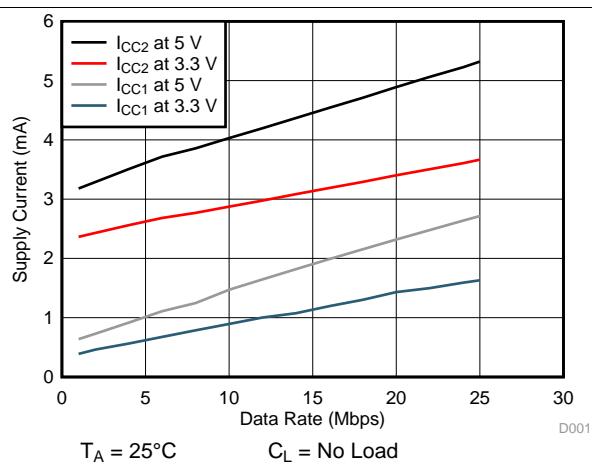
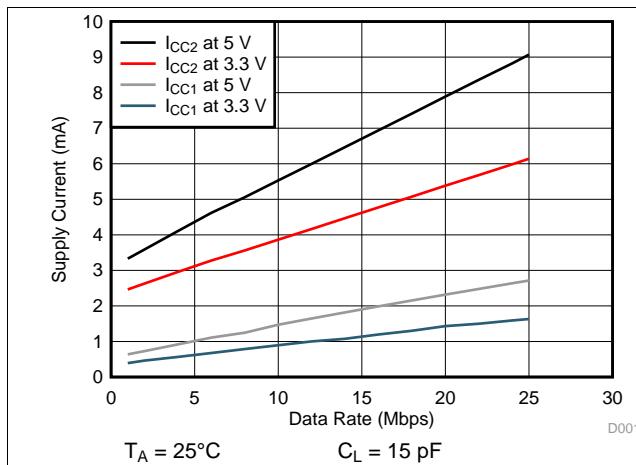
(1) Also known as Pulse Skew.

(2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.

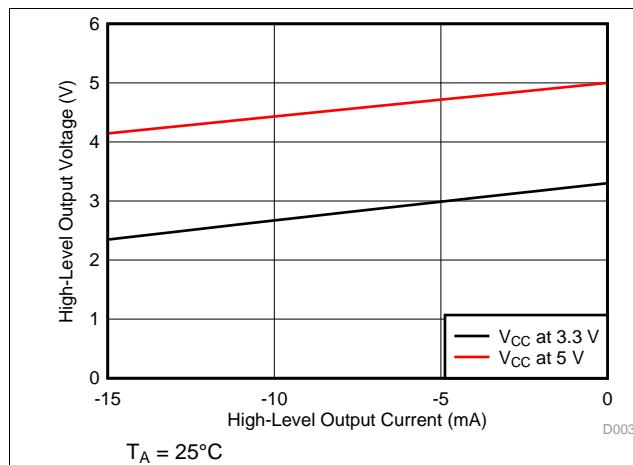
(3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

(4) The enable signal rate should be  $\leq 45\text{ Kbps}$ .

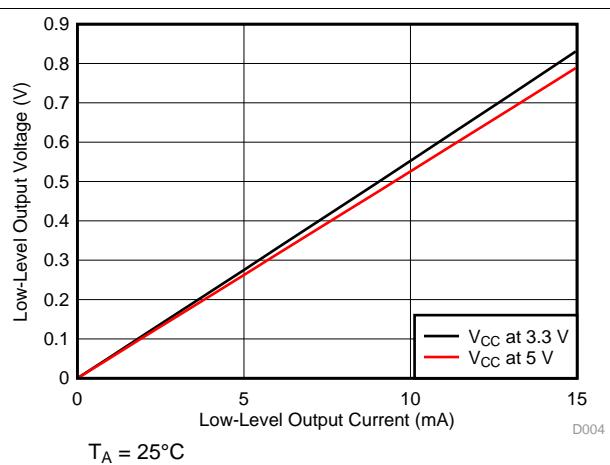
## 6.9 Typical Characteristics



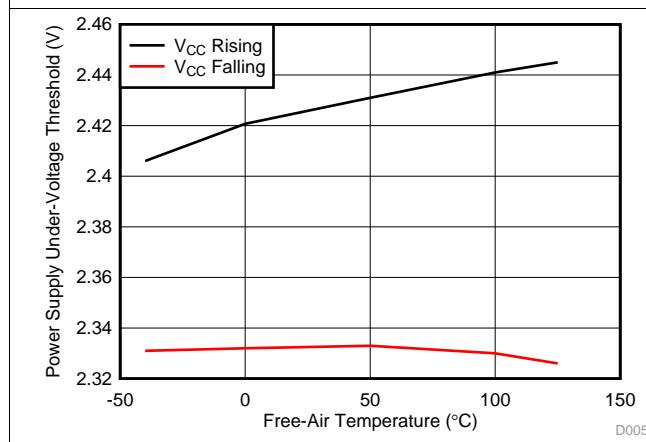
## Typical Characteristics (continued)



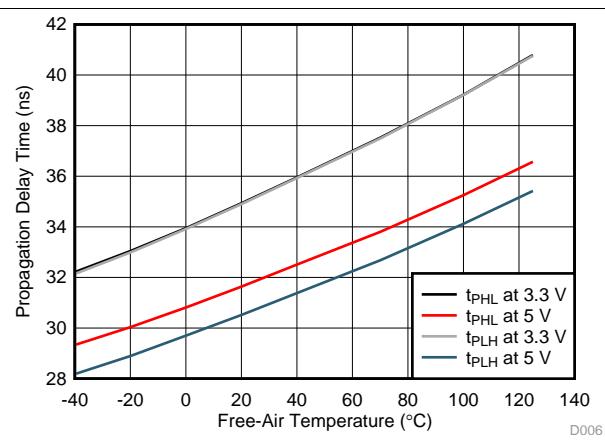
**Figure 7. High-Level Output Voltage vs High-level Output Current**



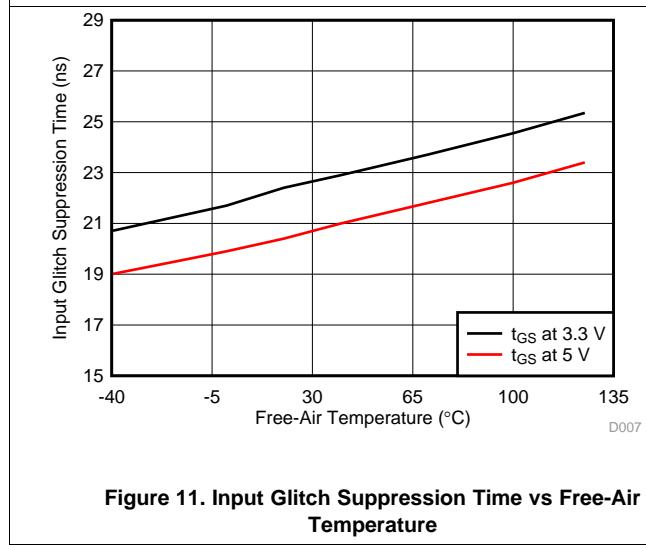
**Figure 8. Low-Level Output Voltage vs Low-Level Output Current**



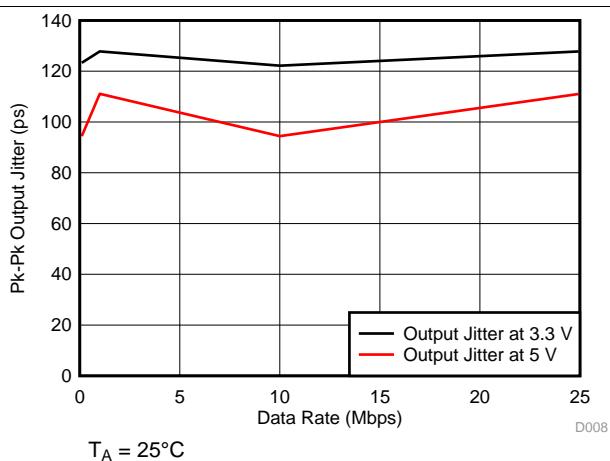
**Figure 9. Power Supply Undervoltage Threshold vs Free-Air Temperature**



**Figure 10. Propagation Delay Time vs Free-Air Temperature**

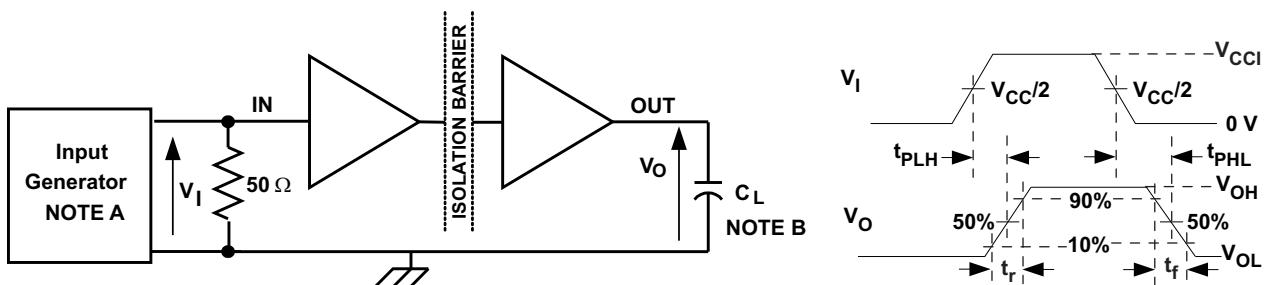


**Figure 11. Input Glitch Suppression Time vs Free-Air Temperature**



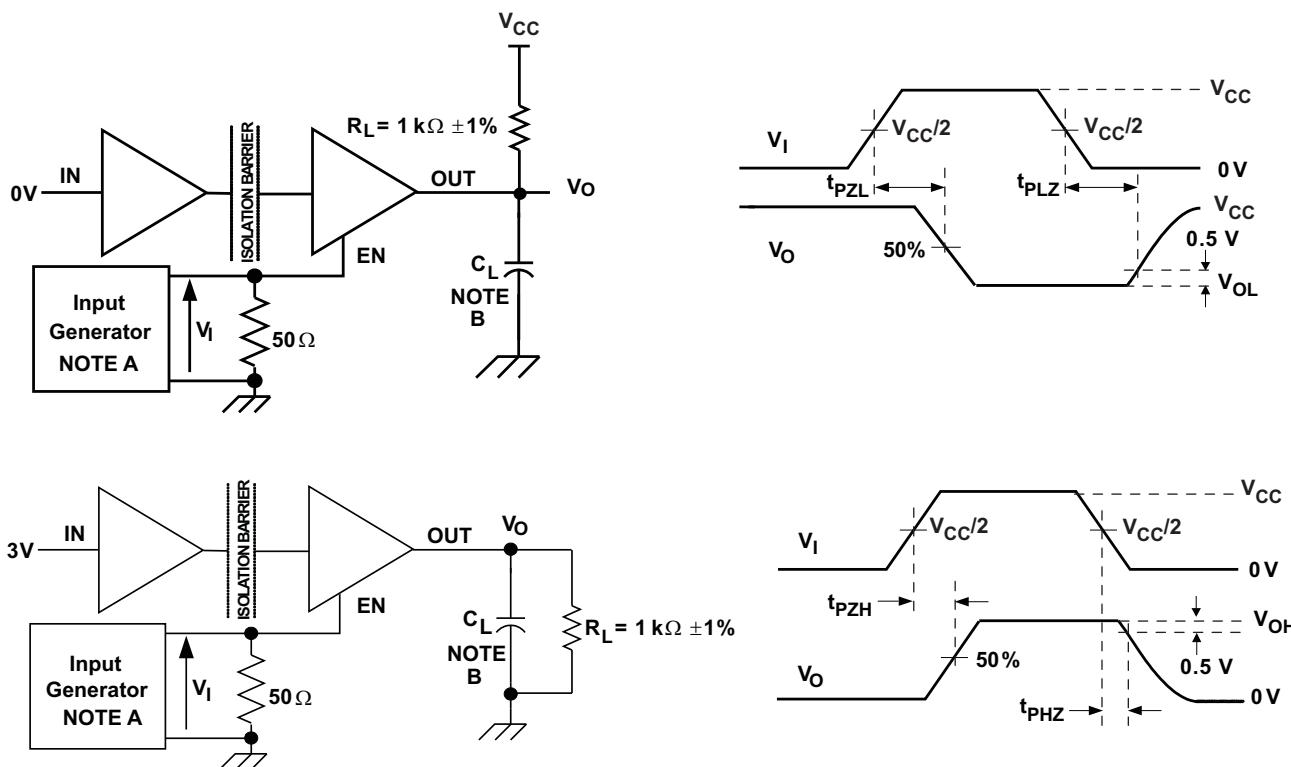
**Figure 12. Output Jitter vs Data Rate**

## 7 Parameter Measurement Information



- A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  50 kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50 \Omega$ . At the input, 50  $\Omega$  resistor is required to terminate Input Generator signal. It is not needed in actual application.
- B.  $C_L = 15 \text{ pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

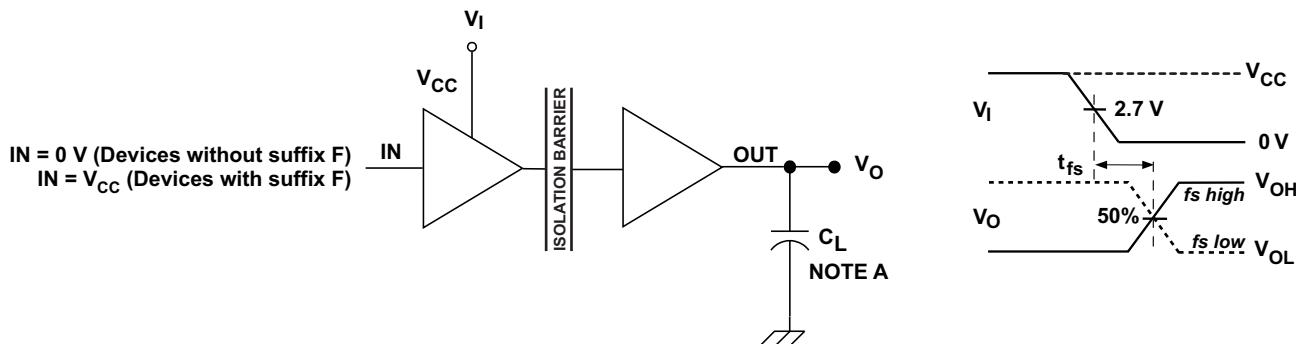
**Figure 13. Switching Characteristics Test Circuit and Voltage Waveforms**



- A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  10 kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50 \Omega$ .
- B.  $C_L = 15 \text{ pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

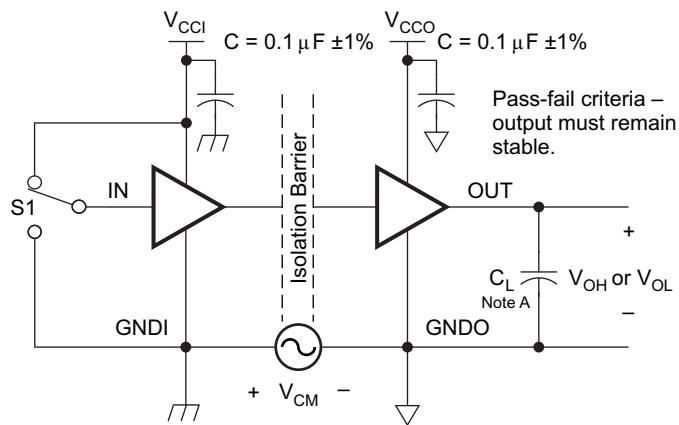
**Figure 14. Enable/Disable Propagation Delay Time Test Circuit and Waveform**

### Parameter Measurement Information (continued)



A.  $C_L = 15 \text{ pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 15. Failsafe Delay Time Test Circuit and Voltage Waveforms**



A.  $C_L = 15 \text{ pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 16. Common-Mode Transient Immunity Test Circuit**

## 8 Detailed Description

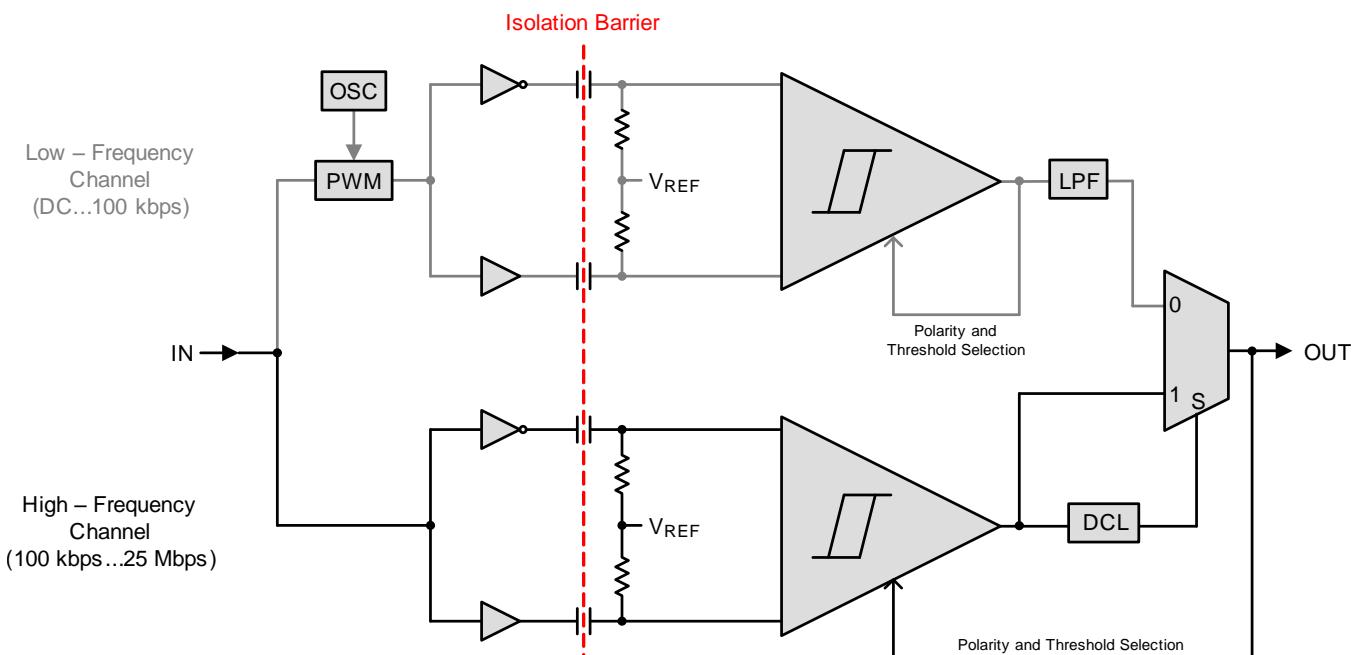
### 8.1 Overview

The isolator in Figure 17 is based on a capacitive isolation barrier technique. The I/O channel of the device consists of two internal data channels, a high-frequency (HF) channel with a bandwidth from 100 kbps up to 25 Mbps, and a low-frequency (LF) channel covering the range from 100 kbps down to DC.

In principle, a single-ended input signal entering the HF channel is split into a differential signal via the inverter gate at the input. The following capacitor-resistor networks differentiate the signal into transient pulses, which then are converted into CMOS levels by a comparator. The transient pulses at the input of the comparator can be either above or below the common mode voltage V<sub>REF</sub> depending on whether the input bit transitioned from 0 to 1 or 1 to 0. The comparator threshold is adjusted based on the expected bit transition. A decision logic (DCL) at the output of the HF channel comparator measures the durations between signal transients. If the duration between two consecutive transients exceeds a certain time limit, (as in the case of a low-frequency signal), the DCL forces the output-multiplexer to switch from the high-frequency to the low-frequency channel.

Because low-frequency input signals require the internal capacitors to assume prohibitively large values, these signals are pulse-width modulated (PWM) with the carrier frequency of an internal oscillator, thus creating a sufficiently high frequency, capable of passing the capacitive barrier. As the input is modulated, a low-pass filter (LPF) is needed to remove the high-frequency carrier from the actual data before passing it on to the output multiplexer.

### 8.2 Functional Block Diagram



**Figure 17. Conceptual Block Diagram of a Digital Capacitive Isolator**

## 8.3 Feature Description

ISO734x are available in multiple channel configurations and default output state options to enable wide variety of application uses.

PRODUCT	CHANNEL DIRECTION	RATED ISOLATION	MAX DATA RATE	DEFAULT OUTPUT
ISO7340C	4 Forward, 0 Reverse	3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> <sup>(1)</sup>	25 Mbps	High
ISO7340FC				Low
ISO7341C				High
ISO7341FC				Low
ISO7342C				High
ISO7342FC				Low

(1) See the [Regulatory Information](#) section for detailed isolation ratings.

### 8.3.1 High Voltage Feature Description

#### 8.3.1.1 Insulation and Safety-Related Specifications for DW-16 Package

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
L(I01)	Minimum air gap (clearance)	8			mm
L(I02)	Minimum external tracking (creepage)	8			mm
CTI	Tracking resistance (comparative tracking index)	DIN EN 60112 (VDE 0303-11); IEC 60112	400		V
DTI	Minimum internal gap (internal clearance)	Distance through the insulation	13		μm
R <sub>IO</sub>	Isolation resistance, input to output <sup>(1)</sup>	V <sub>IO</sub> = 500 V, T <sub>A</sub> = 25°C	10 <sup>12</sup>		Ω
		V <sub>IO</sub> = 500 V, 100°C ≤ T <sub>A</sub> ≤ 125°C	10 <sup>11</sup>		
C <sub>IO</sub>	Isolation capacitance, input to output <sup>(1)</sup>	V <sub>IO</sub> = 0.4 sin (2πft), f = 1 MHz	2.4		pF
C <sub>I</sub>	Input capacitance <sup>(2)</sup>	V <sub>I</sub> = V <sub>CC</sub> /2 + 0.4 sin (2πft), f = 1 MHz, V <sub>CC</sub> = 5 V	3.4		pF

(1) All pins on each side of the barrier tied together creating a two-terminal device.

(2) Measured from input pin to ground.

#### NOTE

Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed-circuit board do not reduce this distance.

Creepage and clearance on a printed-circuit board become equal in certain cases. Techniques such as inserting grooves and/or ribs on a printed circuit board are used to help increase these specifications.

### 8.3.1.2 Insulation Characteristics

over recommended operating conditions (unless otherwise noted)

<b>PARAMETER<sup>(1)</sup></b>		<b>TEST CONDITIONS</b>	<b>SPECIFICATION</b>	<b>UNIT</b>
$V_{IOWM}$	Maximum isolation working voltage		1000	$V_{RMS}$
$V_{IORM}$	Maximum repetitive peak isolation voltage per DIN V VDE V 0884-10		1414	$V_{PK}$
$V_{PR}$	Input-to-output test voltage per DIN V VDE V 0884-10	After Input/Output safety test subgroup 2/3, $V_{PR} = V_{IORM} \times 1.2$ , $t = 10$ s, Partial discharge < 5 pC	1697	$V_{PK}$
		Method a, After environmental tests subgroup 1, $V_{PR} = V_{IORM} \times 1.6$ , $t = 10$ s, Partial Discharge < 5 pC	2262	
		Method b1, $V_{PR} = V_{IORM} \times 1.875$ , $t = 1$ s (100% Production test) Partial discharge < 5 pC	2651	
$V_{IOTM}$	Maximum transient overvoltage per DIN V VDE V 0884-10	$V_{TEST} = V_{IOTM}$ $t = 60$ sec (qualification) $t = 1$ sec (100% production)	4242	$V_{PK}$
$V_{IOSM}$	Maximum surge isolation voltage per DIN V VDE V 0884-10	Test method per IEC 60065, 1.2/50 $\mu$ s waveform, $V_{TEST} = 1.3 \times V_{IOSM} = 7800 V_{PK}$ (qualification)	6000	$V_{PK}$
$V_{ISO}$	Withstand isolation voltage per UL 1577	$V_{TEST} = V_{ISO} = 3000 V_{RMS}$ , $t = 60$ sec (qualification) $V_{TEST} = 1.2 \times V_{ISO} = 3600 V_{RMS}$ , $t = 1$ sec (100% production)	3000	$V_{RMS}$
$R_S$	Insulation resistance	$V_{IO} = 500$ V at $T_S = 150^\circ\text{C}$	>10 <sup>9</sup>	$\Omega$
	Pollution degree		2	

(1) Climatic Classification 40/125/21

**Table 1. IEC 60664-1 Ratings Table**

<b>PARAMETER</b>	<b>TEST CONDITIONS</b>	<b>SPECIFICATION</b>
Basic isolation group	Material group	II
Installation classification	Rated mains voltage ≤ 300 $V_{RMS}$	I-IV
	Rated mains voltage ≤ 600 $V_{RMS}$	I-III
	Rated mains voltage ≤ 1000 $V_{RMS}$	I-II

### 8.3.1.3 Regulatory Information

<b>VDE</b>	<b>CSA</b>	<b>UL</b>	<b>CQC</b>
Certified according to DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 and DIN EN 61010-1 (VDE 0411-1):2011-07	Approved under CSA Component Acceptance Notice 5A, IEC 60950-1, and IEC 61010-1	Recognized under UL 1577 Component Recognition Program	Certified according to GB4943.1-2011
Basic Insulation; Maximum Transient Overvoltage, 4242 $V_{PK}$ ; Maximum Surge Isolation Voltage , 6000 $V_{PK}$ ; Maximum Repetitive Peak Isolation Voltage, 1414 $V_{PK}$	800 $V_{RMS}$ Basic Insulation and 400 $V_{RMS}$ Reinforced Insulation working voltage per CSA 60950-1-07+A1+A2 and IEC 60950-1 2nd Ed.+A1+A2; 300 $V_{RMS}$ Basic Insulation working voltage per CSA 61010-1-12 and IEC 61010-1 3rd Ed.	Single protection, 3000 $V_{RMS}$ <sup>(1)</sup>	Reinforced Insulation, Altitude ≤ 5000 m, Tropical Climate, 250 $V_{RMS}$ maximum working voltage
Certificate number: 40016131	Master contract number: 220991	File number: E181974	Certificate number: CQC15001121716

(1) Production tested ≥ 3600  $V_{RMS}$  for 1 second in accordance with UL 1577.

### 8.3.1.4 Safety Limiting Values

Safety limiting intends to prevent potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the I/O can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier, potentially leading to secondary system failures.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Is Safety input, output, or supply current	R <sub>θJA</sub> = 78.4 °C/W, V <sub>I</sub> = 5.5 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C			290	mA
	R <sub>θJA</sub> = 78.4 °C/W, V <sub>I</sub> = 3.6 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C			443	
T <sub>S</sub> Maximum case temperature				150	°C

The safety-limiting constraint is the absolute-maximum junction temperature specified in the [Absolut Maximum Ratings](#) table. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determines the junction temperature. The assumed junction-to-air thermal resistance in the [Thermal Information](#) table is that of a device installed on a High-K Test Board for Leaded Surface-Mount Packages. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.

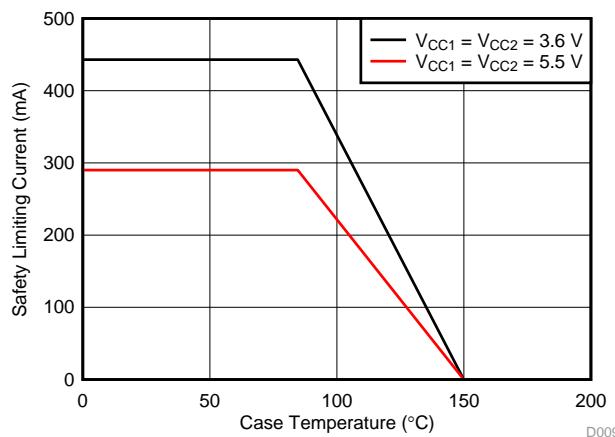


Figure 18.  $\theta_{JC}$  Thermal Derating Curve per DIN V VDE 0884-10

## 8.4 Device Functional Modes

ISO734x functional modes are shown in [Table 2](#).

Table 2. Function Table<sup>(1)</sup>

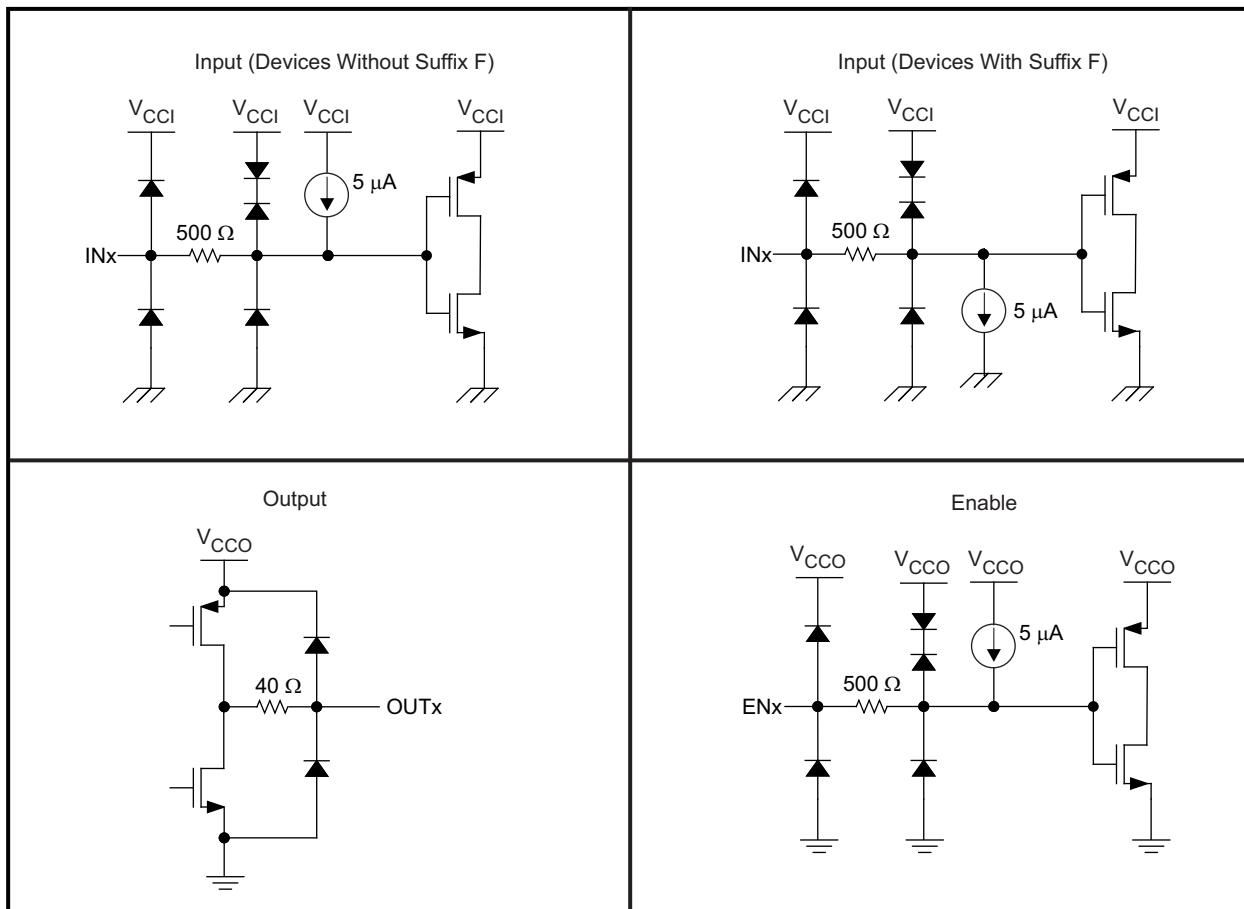
V <sub>CCI</sub>	V <sub>CCO</sub>	INPUT (IN <sub>x</sub> )	OUTPUT ENABLE (EN <sub>x</sub> )	OUTPUT (OUT <sub>x</sub> )	
				ISO734xC	ISO734xF
PU	PU	H	H or Open	H	H
		L	H or Open	L	L
		X	L	Z	Z
		Open	H or Open	H <sup>(2)</sup>	L <sup>(3)</sup>
PD	PU	X	H or Open	H <sup>(2)</sup>	L <sup>(3)</sup>
X	PU	X	L	Z	Z
X	PD	X	X	Undetermined	Undetermined

(1) V<sub>CCI</sub> = Input-side V<sub>CC</sub>; V<sub>CCO</sub> = Output-side V<sub>CC</sub>; PU = Powered up (V<sub>CC</sub> ≥ 3 V); PD = Powered down (V<sub>CC</sub> ≤ 2.1 V); X = Irrelevant; H = High level; L = Low level; Z = High Impedance

(2) In fail-safe condition, output defaults to high level

(3) In fail-safe condition, output defaults to low level

#### 8.4.1 Device I/O Schematics



**Figure 19. Device I/O Schematics**

## 9 Applications and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

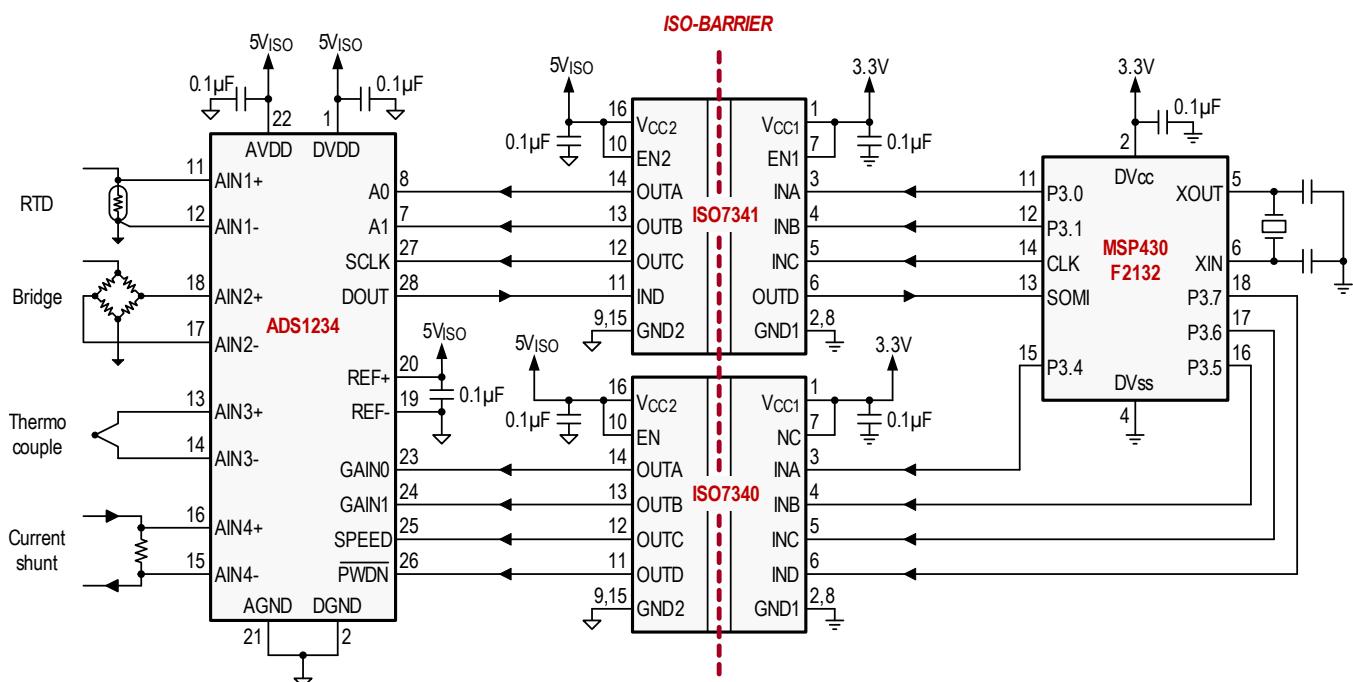
### 9.1 Application Information

ISO734x use single-ended TTL-logic switching technology. Its supply voltage range is from 3 V to 5.5 V for both supplies,  $V_{CC1}$  and  $V_{CC2}$ . When designing with digital isolators, it is important to note that due to the single-ended design structure, digital isolators do not conform to any specific interface standard and are only intended for isolating single-ended CMOS or TTL digital signal lines. The isolator is typically placed between the data controller (that is,  $\mu$ C or UART), and a data converter or a line transceiver, regardless of the interface type or standard.

### 9.2 Typical Application

#### 9.2.1 Isolated Data Acquisition System for Process Control

ISO734x combined with Texas Instruments' precision analog-to-digital converter and mixed signal microcontroller can create an advanced isolated data acquisition system as shown in Figure 20.



**Figure 20. Isolated Data Acquisition System for Process Control**

## Typical Application (continued)

### 9.2.1.1 Design Requirements

#### 9.2.1.1.1 Typical Supply Current Equations

##### 9.2.1.1.1.1 ISO7340

At  $V_{CC1} = V_{CC2} = 5 \text{ V}$

$$I_{CC1} = 0.54366 + (0.0873 \times f) \quad (1)$$

$$I_{CC2} = 2.74567 + (0.08433 \times f) + (0.01 \times f \times C_L) \quad (2)$$

At  $V_{CC1} = V_{CC2} = 3.3 \text{ V}$

$$I_{CC1} = 0.3437 + (0.04922 \times f) \quad (3)$$

$$I_{CC2} = 2.1068 + (0.04374 \times f) + (0.007045 \times f \times C_L) \quad (4)$$

##### 9.2.1.1.1.2 ISO7341

At  $V_{CC1} = V_{CC2} = 5 \text{ V}$

$$I_{CC1} = 1.7403 + (0.1006 \times f) + (0.001711 \times f \times C_L) \quad (5)$$

$$I_{CC2} = 2.502 + (0.09629 \times f) + (0.00687 \times f \times C_L) \quad (6)$$

At  $V_{CC1} = V_{CC2} = 3.3 \text{ V}$

$$I_{CC1} = 1.2915 + (0.046 \times f) + (0.00185 \times f \times C_L) \quad (7)$$

$$I_{CC2} = 1.8833 + (0.0566 \times f) + (0.004514 \times f \times C_L) \quad (8)$$

##### 9.2.1.1.1.3 ISO7342

At  $V_{CC1} = V_{CC2} = 5 \text{ V}$

$$I_{CC1}, I_{CC2} = 2.1254 + (0.08694 \times f) + (0.004868 \times f \times C_L) \quad (9)$$

At  $V_{CC1} = V_{CC2} = 3.3 \text{ V}$

$$I_{CC1}, I_{CC2} = 1.5912 + (0.0410 \times f) + (0.003785 \times f \times C_L) \quad (10)$$

$I_{CC1}$  and  $I_{CC2}$  are typical supply currents measured in mA,  $f$  is data rate measured in Mbps,  $C_L$  is the capacitive load measured in pF.

### 9.2.1.2 Detailed Design Procedure

Unlike optocouplers, which need external components to improve performance, provide bias, or limit current, ISO734x only needs two external bypass capacitors to operate.

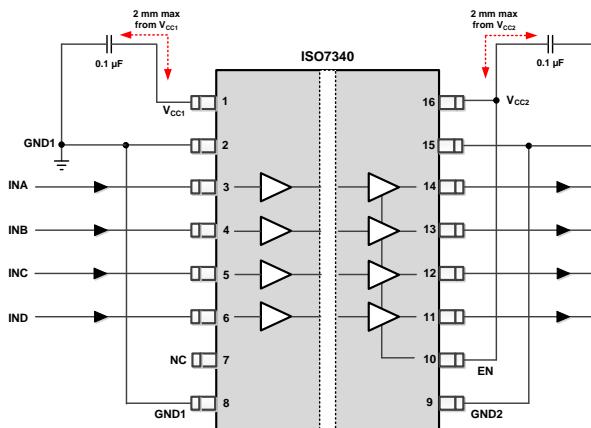


Figure 21. Typical ISO7340 Circuit Hook-up

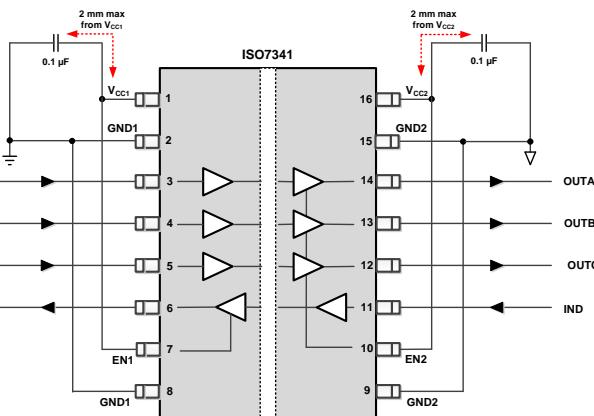
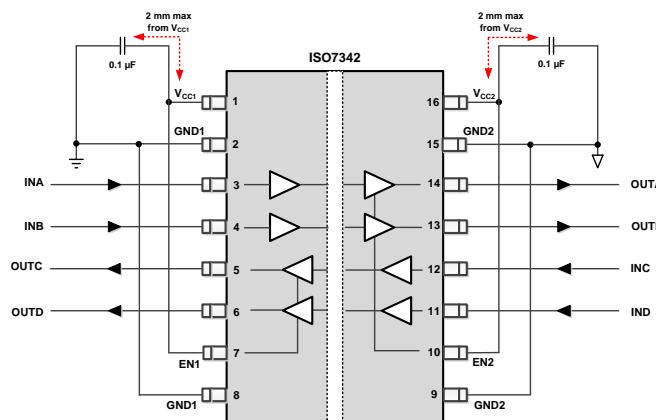


Figure 22. Typical ISO7341 Circuit Hook-up

## Typical Application (continued)



**Figure 23. Typical ISO7342 Circuit Hook-up**

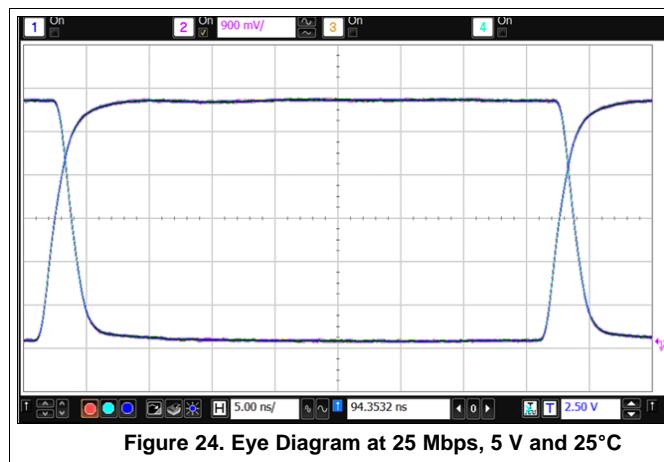
### 9.2.1.2.1 Electromagnetic Compatibility (EMC) Considerations

Many applications in harsh industrial environment are sensitive to disturbances such as electrostatic discharge (ESD), electrical fast transient (EFT), surge and electromagnetic emissions. These electromagnetic disturbances are regulated by international standards such as IEC 61000-4-x and CISPR 22. Although system-level performance and reliability depends, to a large extent, on the application board design and layout, the ISO734x incorporate many chip-level design improvements for overall system robustness. Some of these improvements include:

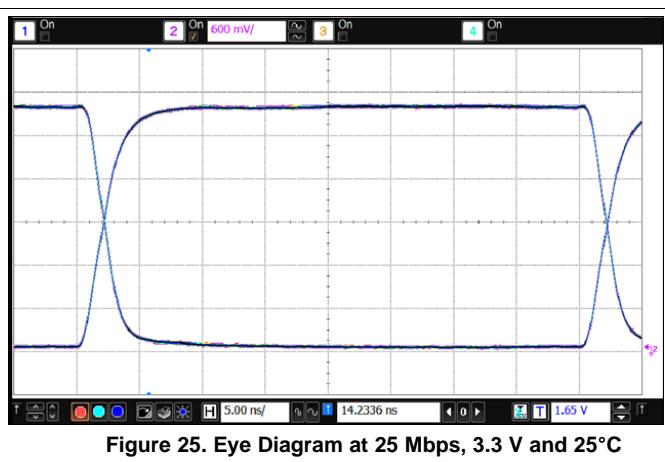
- Robust ESD protection cells for input and output signal pins and inter-chip bond pads.
- Low-resistance connectivity of ESD cells to supply and ground pins.
- Enhanced performance of high voltage isolation capacitor for better tolerance of ESD, EFT and surge events.
- Bigger on-chip decoupling capacitors to bypass undesirable high energy signals through a low impedance path.
- PMOS and NMOS devices isolated from each other by using guard rings to avoid triggering of parasitic SCRs.
- Reduced common mode currents across the isolation barrier by ensuring purely differential internal operation.

### 9.2.1.3 Application Performance Curves

Typical eye diagrams of ISO734x indicate low jitter and wide open eye at the maximum data rate of 25 Mbps.



**Figure 24. Eye Diagram at 25 Mbps, 5 V and 25°C**

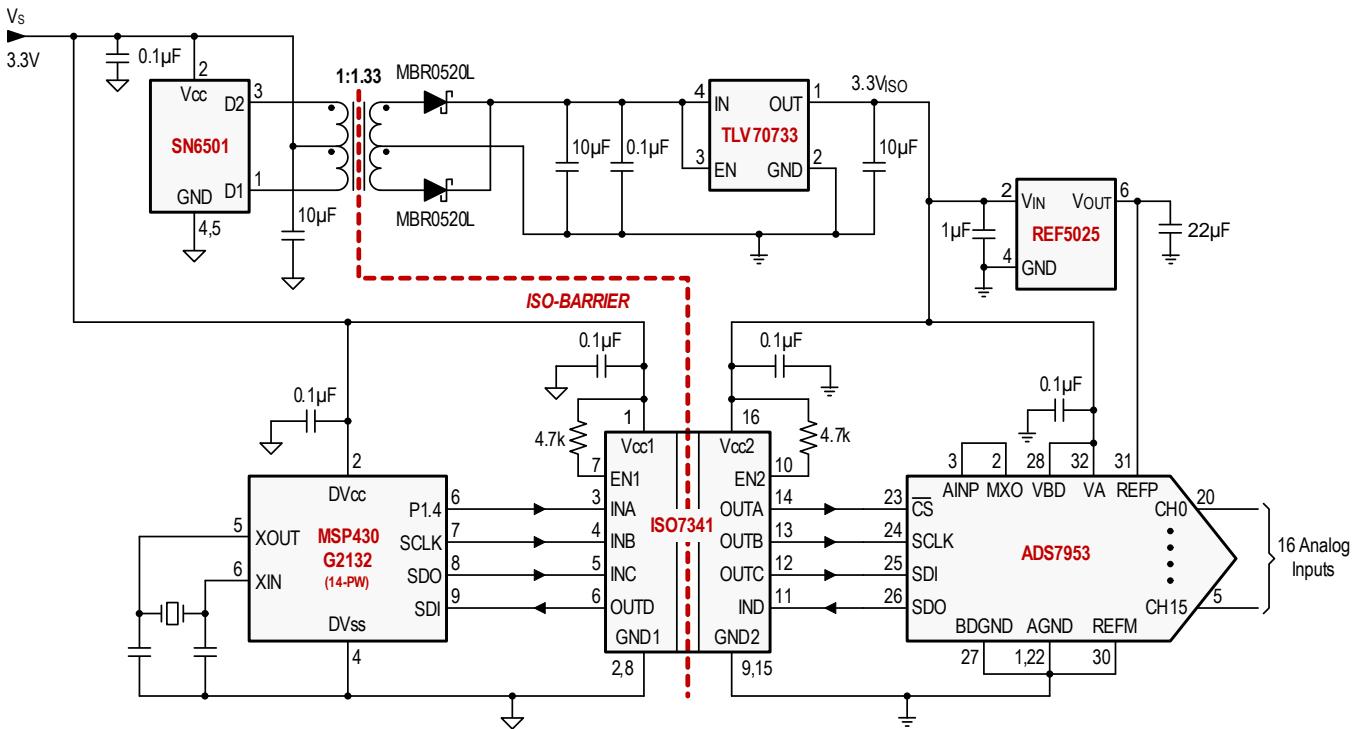


**Figure 25. Eye Diagram at 25 Mbps, 3.3 V and 25°C**

## Typical Application (continued)

### 9.2.2 Typical Application for Module with 16 Inputs

ISO7341 and several other components from Texas Instruments can be used to create an isolated SPI interface for input module with 16 inputs.



**Figure 26. Isolated SPI Interface for an Analog Input Module With 16 Inputs**

#### 9.2.2.1 Design Requirements

Refer to [Isolated Data Acquisition System for Process Control](#) for the design requirements.

#### 9.2.2.2 Detailed Design Procedure

Refer to [Isolated Data Acquisition System for Process Control](#) for the detailed design procedures.

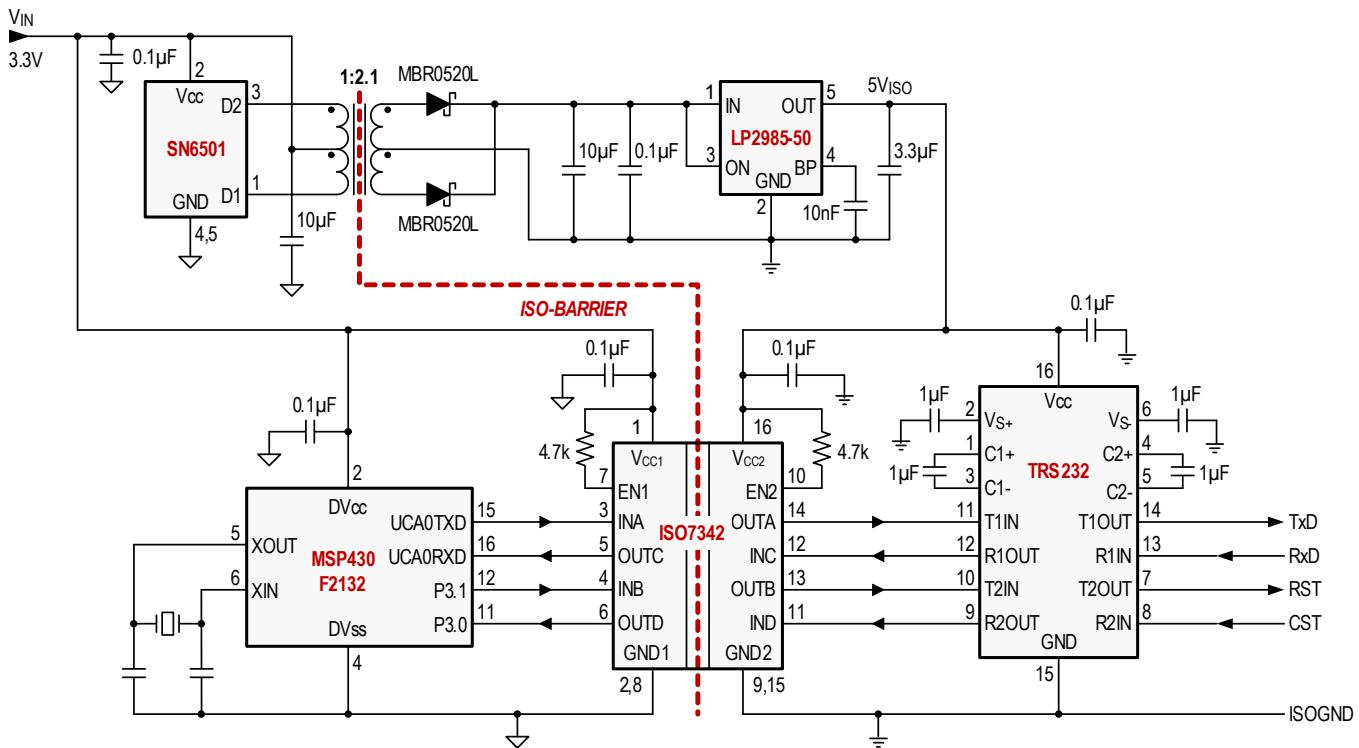
#### 9.2.2.3 Application Performance Curves

Refer to [Isolated Data Acquisition System for Process Control](#) for the application performance curves.

## Typical Application (continued)

### 9.2.3 Typical Application for RS-232 Interface

Typical isolated RS-232 interface implementation is shown in [Figure 27](#).



**Figure 27.** Isolated RS-232 Interface

#### 9.2.3.1 Design Requirements

Refer to [Isolated Data Acquisition System for Process Control](#) for the design requirements.

#### 9.2.3.2 Detailed Design Procedure

Refer to [Isolated Data Acquisition System for Process Control](#) for the detailed design procedures.

#### 9.2.3.3 Application Performance Curves

Refer to [Isolated Data Acquisition System for Process Control](#) for the application performance curves.

## 10 Power Supply Recommendations

To ensure reliable operation at all data rates and supply voltages, a  $0.1\ \mu F$  bypass capacitor is recommended at input and output supply pins ( $V_{CC1}$  and  $V_{CC2}$ ). The capacitors should be placed as close to the supply pins as possible. If only a single primary-side power supply is available in an application, isolated power can be generated for the secondary-side with the help of a transformer driver such as Texas Instruments' [SN6501](#). For such applications, detailed power supply design and transformer selection recommendations are available in [SN6501 datasheet \(SLLSEA0\)](#).

## 11 Layout

### 11.1 PCB Material

For digital circuit boards operating below 150 Mbps, (or rise and fall times higher than 1 ns), and trace lengths of up to 10 inches, use standard FR-4 epoxy-glass as PCB material. FR-4 (Flame Retardant 4) meets the requirements of Underwriters Laboratories UL94-V0, and is preferred over cheaper alternatives due to its lower dielectric losses at high frequencies, less moisture absorption, greater strength and stiffness, and its self-extinguishing flammability-characteristics.

### 11.2 Layout Guidelines

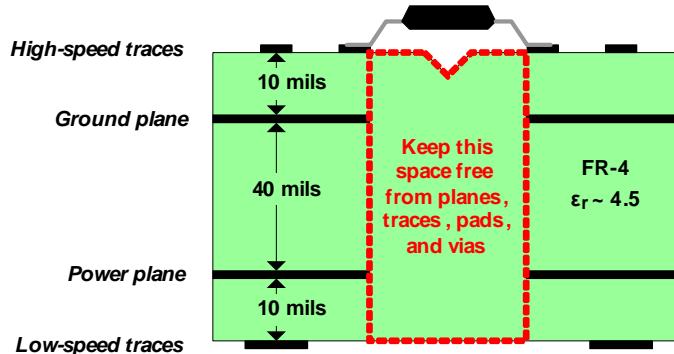
A minimum of four layers is required to accomplish a low EMI PCB design (see [Figure 28](#)). Layer stacking should be in the following order (top-to-bottom): high-speed signal layer, ground plane, power plane and low-frequency signal layer.

- Routing the high-speed traces on the top layer avoids the use of vias (and the introduction of their inductances) and allows for clean interconnects between the isolator and the transmitter and receiver circuits of the data link.
- Placing a solid ground plane next to the high-speed signal layer establishes controlled impedance for transmission line interconnects and provides an excellent low-inductance path for the return current flow.
- Placing the power plane next to the ground plane creates additional high-frequency bypass capacitance of approximately  $100\text{pF/in}^2$ .
- Routing the slower speed control signals on the bottom layer allows for greater flexibility as these signal links usually have margin to tolerate discontinuities such as vias.

If an additional supply voltage plane or signal layer is needed, add a second power / ground plane system to the stack to keep it symmetrical. This makes the stack mechanically stable and prevents it from warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high-frequency bypass capacitance significantly.

For detailed layout recommendations, see Application Note [SLLA284, Digital Isolator Design Guide](#).

### 11.3 Layout Example



**Figure 28. Recommended Layer Stack**

## 12 Device and Documentation Support

### 12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 3. Related Links**

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
ISO7340C	<a href="#">Click here</a>				
ISO7340FC	<a href="#">Click here</a>				
ISO7341C	<a href="#">Click here</a>				
ISO7341FC	<a href="#">Click here</a>				
ISO7342C	<a href="#">Click here</a>				
ISO7342FC	<a href="#">Click here</a>				

### 12.2 Trademarks

All trademarks are the property of their respective owners.

### 12.3 Electrostatic Discharge Caution

 These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.4 Glossary

[SLYZ022 — TI Glossary](#).

This glossary lists and explains terms, acronyms, and definitions.

*Isolation Glossary*, [SLLS353](#)

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

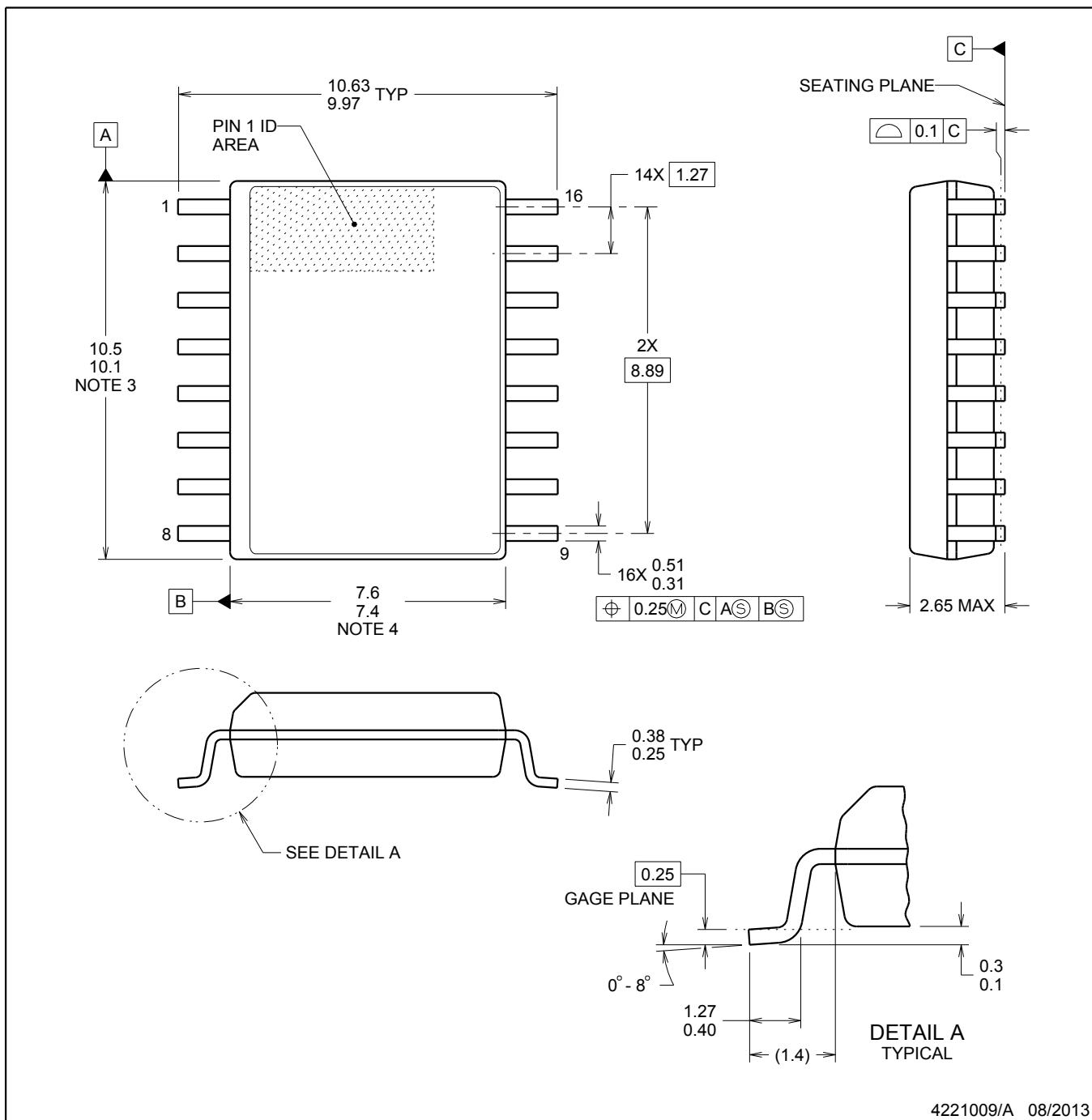
# PACKAGE OUTLINE



DW0016B

SOIC - 2.65 mm max height

SOIC



4221009/A 08/2013

## NOTES:

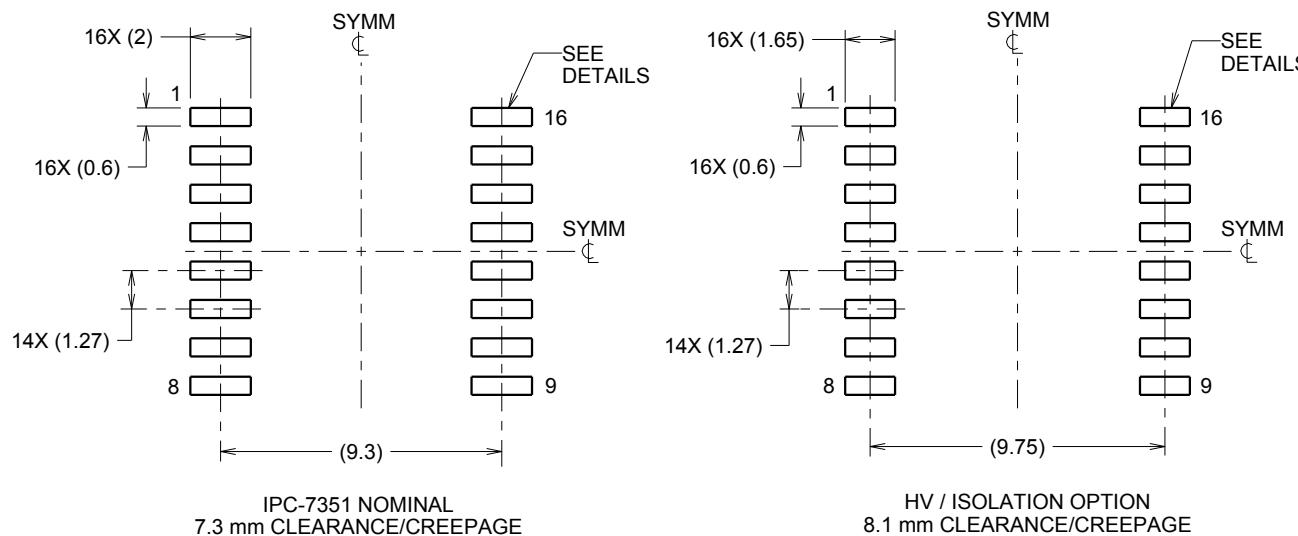
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MO-013, variation AA.

# EXAMPLE BOARD LAYOUT

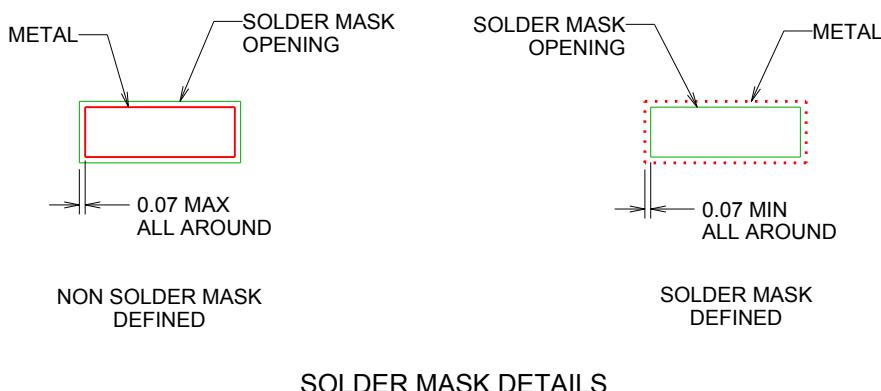
DW0016B

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:4X



SOLDER MASK DETAILS

4221009/A 08/2013

NOTES: (continued)

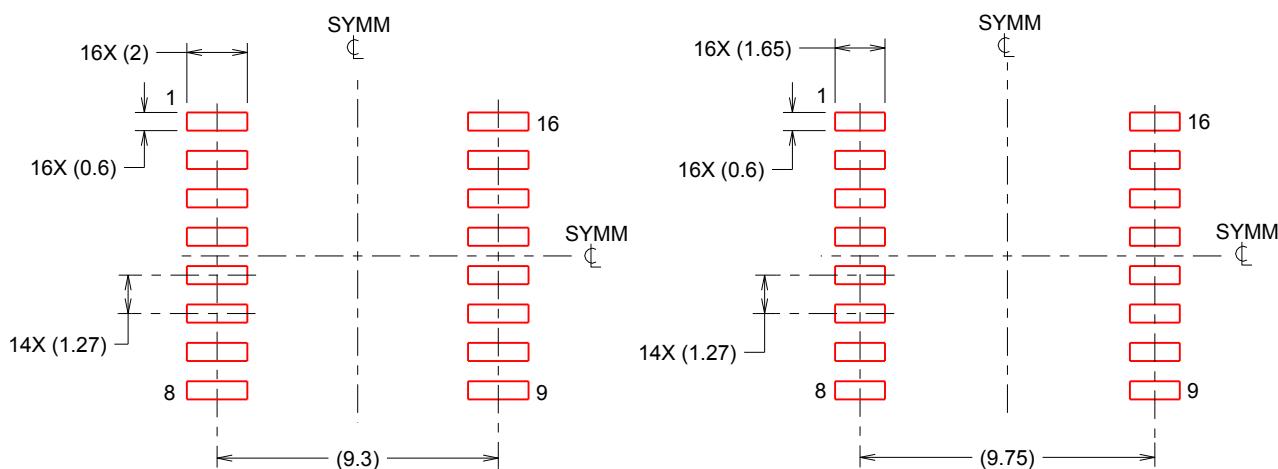
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DW0016B

SOIC - 2.65 mm max height

SOIC



IPC-7351 NOMINAL  
7.3 mm CLEARANCE/CREEPAGE

HV / ISOLATION OPTION  
8.1 mm CLEARANCE/CREEPAGE

SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:4X

4221009/A 08/2013

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ISO7340CDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7340C	<span style="background-color: red; color: white;">Samples</span>
ISO7340CDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7340C	<span style="background-color: red; color: white;">Samples</span>
ISO7340FCDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7340FC	<span style="background-color: red; color: white;">Samples</span>
ISO7340FCDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7340FC	<span style="background-color: red; color: white;">Samples</span>
ISO7341CDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7341C	<span style="background-color: red; color: white;">Samples</span>
ISO7341CDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7341C	<span style="background-color: red; color: white;">Samples</span>
ISO7341FCDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7341FC	<span style="background-color: red; color: white;">Samples</span>
ISO7341FCDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7341FC	<span style="background-color: red; color: white;">Samples</span>
ISO7342CDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7342C	<span style="background-color: red; color: white;">Samples</span>
ISO7342CDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7342C	<span style="background-color: red; color: white;">Samples</span>
ISO7342FCDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7342FC	<span style="background-color: red; color: white;">Samples</span>
ISO7342FCDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ISO7342FC	<span style="background-color: red; color: white;">Samples</span>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

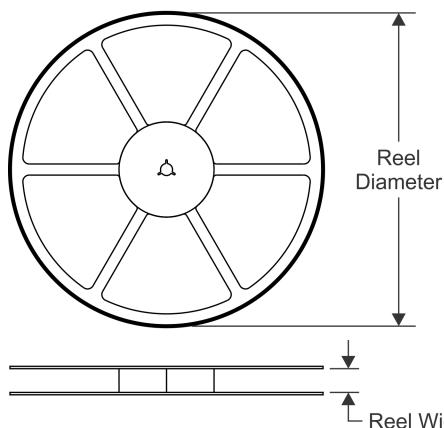
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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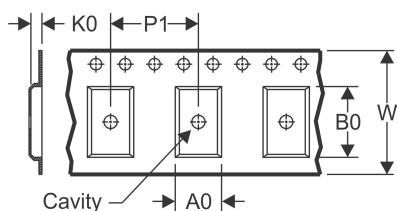
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## TAPE AND REEL INFORMATION

### REEL DIMENSIONS

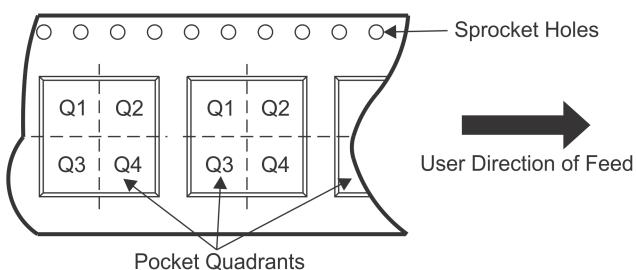


### TAPE DIMENSIONS



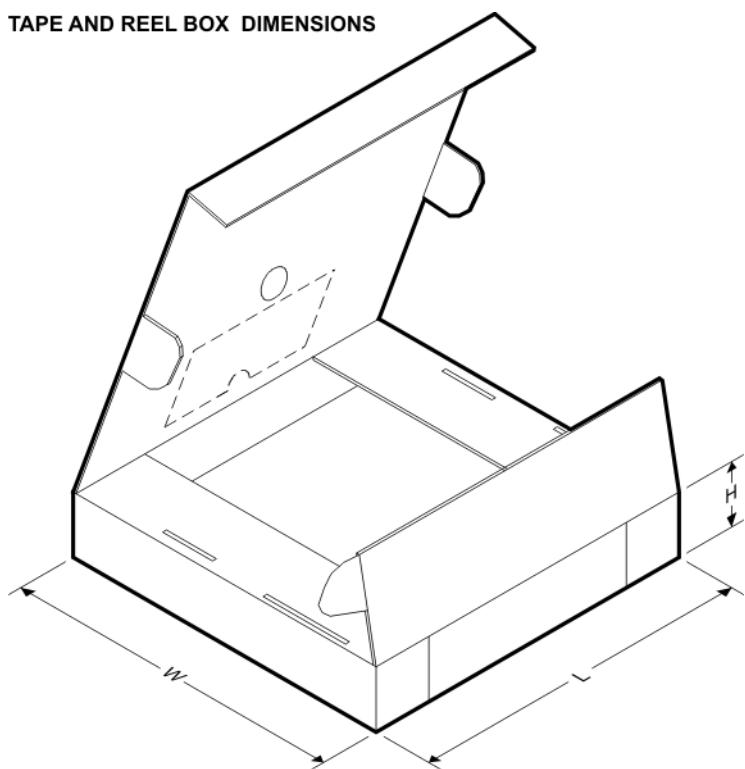
$A_0$	Dimension designed to accommodate the component width
$B_0$	Dimension designed to accommodate the component length
$K_0$	Dimension designed to accommodate the component thickness
$W$	Overall width of the carrier tape
$P_1$	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	$A_0$ (mm)	$B_0$ (mm)	$K_0$ (mm)	$P_1$ (mm)	$W$ (mm)	Pin1 Quadrant
ISO7340CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
ISO7340FCDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
ISO7341CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
ISO7341FCDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
ISO7342CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
ISO7342FCDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ISO7340CDWR	SOIC	DW	16	2000	367.0	367.0	38.0
ISO7340FCDWR	SOIC	DW	16	2000	367.0	367.0	38.0
ISO7341CDWR	SOIC	DW	16	2000	367.0	367.0	38.0
ISO7341FCDWR	SOIC	DW	16	2000	367.0	367.0	38.0
ISO7342CDWR	SOIC	DW	16	2000	367.0	367.0	38.0
ISO7342FCDWR	SOIC	DW	16	2000	367.0	367.0	38.0

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Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>	Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>	Consumer Electronics	<a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>	Energy and Lighting	<a href="http://www.ti.com/energy">www.ti.com/energy</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>	Industrial	<a href="http://www.ti.com/industrial">www.ti.com/industrial</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>	Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>	Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>	Space, Avionics and Defense	<a href="http://www.ti.com/space-avionics-defense">www.ti.com/space-avionics-defense</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>	Video and Imaging	<a href="http://www.ti.com/video">www.ti.com/video</a>
RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>	<b>TI E2E Community</b>	
OMAP Applications Processors	<a href="http://www.ti.com/omap">www.ti.com/omap</a>	<a href="http://e2e.ti.com">e2e.ti.com</a>	
Wireless Connectivity	<a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a>		



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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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Факс: 8 (812) 320-02-42

Электронная почта: [org@eplast1.ru](mailto:org@eplast1.ru)

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